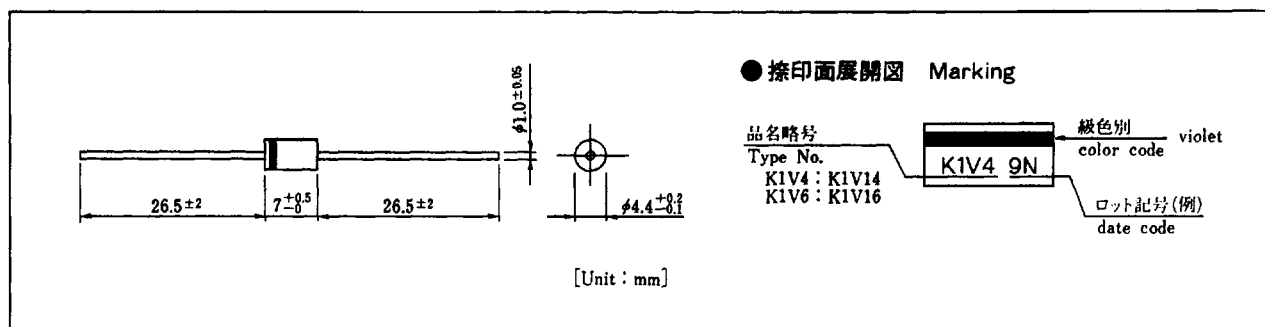


項目 Item	記号 Symbol	条件 Conditions	規格値 Ratings	単位 Unit
保存温度 Storage Temperature	Tstg		-40~125	°C
接合部温度 Operating Junction Temperature	Tj		125	°C
オフ電圧 Maximum Off-state Voltage	VDRM		115	V
実効オン電流 RMS On-state Current	IT	Tj=109°C, 50Hz sine wave ($\theta=180^\circ$)	1	A
サージオン電流 Surge On-state Current	ITSM	Tj=25°C, 50Hz sine wave ($\theta=180^\circ$), non-repetitive 1-cycle peak value	20	A
パルスオン電流 Pulse On-state Current	ITRM	Ta=25°C, pulse width $t_0=10\mu\text{s}$, sine wave, repetitive peak value	f=1kHz 25	A
			f=60Hz 80	
オン電流上昇率 Critical Rate of Rise of On-state Current	diT/dt		80	A/ μs

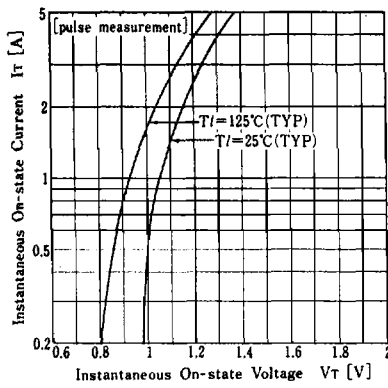
項目 Item	記号 Symbol	条件 Conditions	規格値 Ratings		単位 Unit
			K1V14	K1V16	
ブレイクオーバー電圧 Breakover Voltage	VBO	IB=0, 50Hz sine wave	125~150	145~170	V
オフ電流 Off-state Current	IDRM	VD=VDRM	MAX 10		μA
ブレイクオーバー電流 Breakover Current	IBO		MAX 0.5		mA
保持電流 Holding Current	IH		TYP 30		mA
オン電圧 On-state Voltage	VT	IT=1A	MAX 1.5		V
スイッチング抵抗 Switching Resistance	RS		MIN 0.1		k Ω
熱抵抗 Thermal Resistance	θ_{jl}	Junction to lead	MAX 15		°C/W

項目 Item	記号 Symbol	条件 Conditions	標準値 Standard	単位 Unit
実効オン電流 RMS On-state Current	IT	Assembled in P.C.B., Ta=25°C, soldering land 3mm ϕ	1.04	A

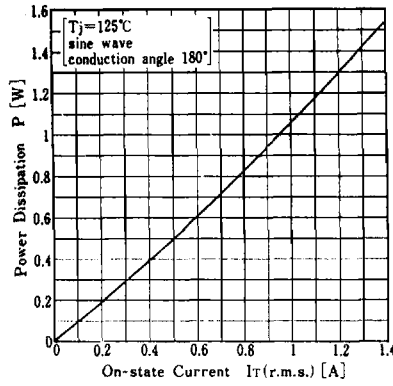


Characteristic Diagrams

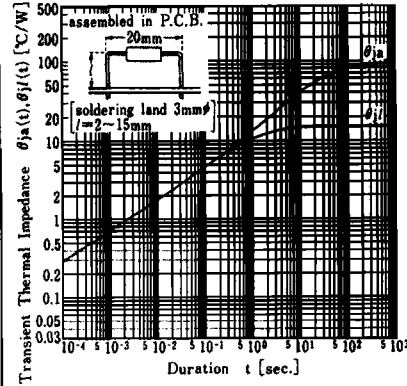
Typical On-state Voltage



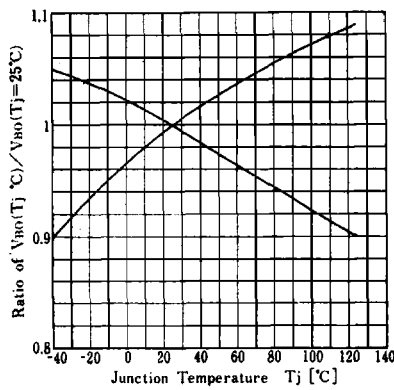
Power Dissipation



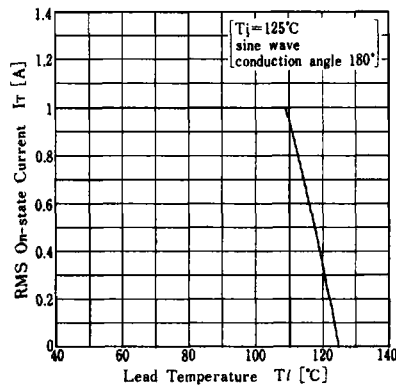
Transient Thermal Impedance



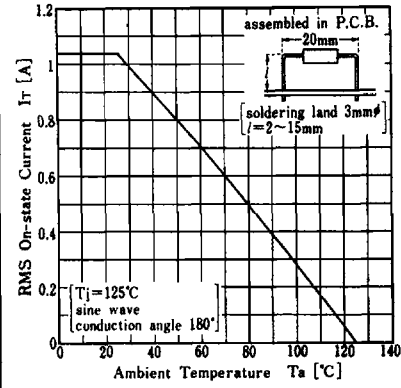
Breakover Voltage VS. T_j



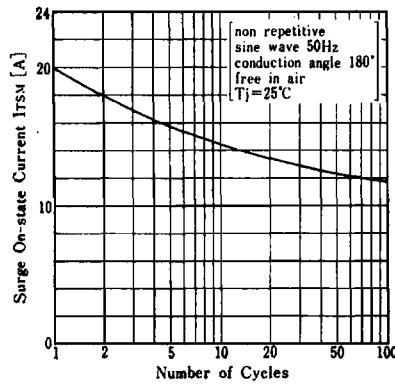
Max. Lead Temperature



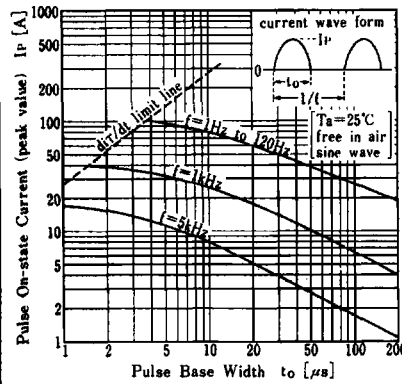
Max. Ambient Temperature



Surge On-state Current (I_TSM)



Pulse On-state Current Rating (I_TRM)



Pulse On-state Current Derating (I_TRM)

